

HI-8190, HI-8191, HI-8192 12Ω, Quad, SPST, 3.3V / 5.0V compatible Analog Switch

October 2017

GENERAL DESCRIPTION

The HI-8190 is a quad analog CMOS switch fabricated with Silicon-on-Insulator (SOI) technology for latch-up free operation and maximum switch isolation. The switch voltages can range from bipolar \pm 3.3V to \pm 15V or single ended from 3.3V to 15V. The logic supply can range from 3.3V to 5.0V. The HI-8190 provides four each normally open switches when the switch control inputs are Low. The HI-8191 provides four each normally closed switches when the switch control inputs are Low. The HI-8191 provides four each normally closed switches when the switch control inputs are Low. The HI-8192 provides a combination of two normally On and two normally Off switches. The limits of the operating range are defined by the V+/V- bias voltage.

On-resistance of each switch depends upon only the VLOGIC selection. At 5V, Ron ranges from 10Ω to 17Ω while at 3.3V supply Ron ranges from 10Ω to 22Ω . Each switch is designed using back to back high voltage transistors. Switch transistors are symmetrical and conduct equally well in either direction. Signal range can run the full rails. Off leakages are very low (1 nA typical) and charge injection is less than 3 pC. Switch ESD tolerance is greater than 4 KV.

The Off state is achieved first before any On condition is applied. Switching times with a 3.3V VLOGIC supply are typically 35 ns to the On state and 20 ns to the Off state.

Industry-standard plastic package options include 16-pin TSSOP, SO, DIP and 16-pin QFN. Ceramic packaging is available on request. All three products are offered in both Industrial (-40°C to +85°C) and extended (-55°C to +125°C) temperature range options.

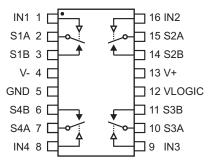
APPLICATIONS

- Data bus isolation
- Sample-and-Hold circuits
- Test Equipment
- Communications Systems
- Battery operated Systems
- PBX, PABX
- Audio Signal Routing
- Data Acquisition Systems
- xDSL Modems
- Avionics

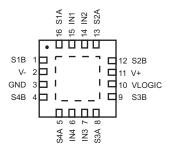
FEATURES

- ± 3.3V to ± 15V CMOS analog switches
- Low RON: 12 Ω to 15 Ω typical
- Robust CMOS Silicon-on-Insulator (SOI) technology
- SOI switch isolation with 1nA typical Off leakage
- Superior ESD protection > 4KV HBM
- Fast switching time with break-before-make
- Low power
- Extended Temperature Range (-55°C to +125°C)

PIN CONFIGURATIONS (Top Views)



HI-8190PSx, HI-8190PDx 16-Pin SO or DIP package

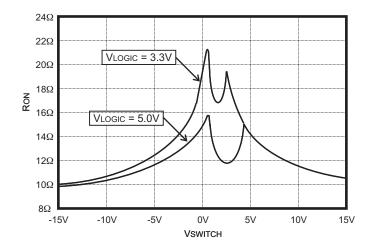


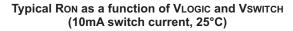
HI-8190PCx 16-pin 5mm x 5mm Chip-scale package

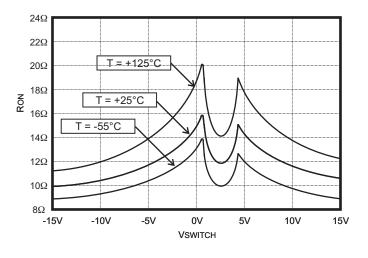
PRODUCT OPTIONS									
PART TYPE	IN1	Switch 1	IN2	Switch 2	IN3	Switch 3	IN4	Switch 4	
HI-8190	0	Open	0	Open	0	Open	0	Open	
	1	Closed	1	Closed	1	Closed	1	Closed	
HI-8191	0	Closed	0	Closed	0	Closed	0	Closed	
	1	Open	1	Open	1	Open	1	Open	
HI-8192	0	Open	0	Closed	0	Closed	0	Open	
	1	Closed	1	Open	1	Open	1	Closed	

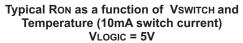
PIN DESCRIPTIONS

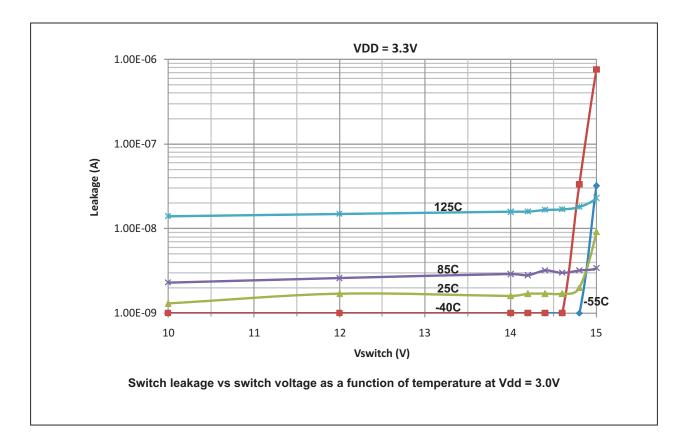
SIGNAL	FUNCTION	DESCRIPTION		
IN1	Logic Input	HI-8190 and HI-8192 are normally Open when input Low		
S1A	Switch Node	Switch 1 Node		
S1B	Switch Node	Switch 1 Node		
V-	Supply	Negative supply for Bipolar configuration. GND for Unipolar use		
GND	Supply	Reference Ground		
S4B	Switch Node	Switch 4 Node		
S4A	Switch Node	Switch 4 Node		
IN4	Logic Input	HI-8190 and HI-8192 are normally Open when input Low		
IN3	Logic Input	HI-8191 and HI-8192 are normally Closed when input Low		
S3A	Switch Node	Switch 3 Node		
S3B	Switch Node	Switch 3 Node		
VLOGIC	Supply	3.3V or 5.0V Logic supply		
V+	Supply	Positive supply for Bipolar and Unipolar configurations		
S2B	Switch Node	Switch 2 Node		
S1B	Switch Node	Switch 2 Node		
IN2	Logic input	nput HI-8191 and HI-8192 are normally Closed when input Low		

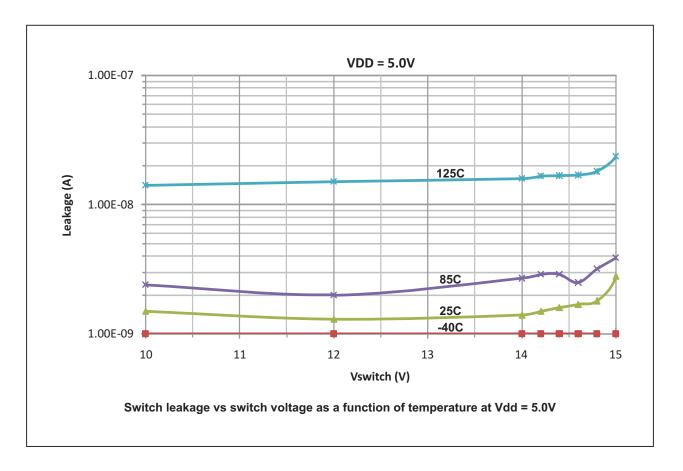












ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to GND = 0V)

Supply Voltage, V+: 16.5V Supply Voltage, V-: -16.5V Supply Volgate, VLOGIC 5.5V Switch Current (either direction, DC): 20mA Peak Switch Current (1 ms pulse, 10% duty cycle max.) 100mA Digital Input Voltage (IN1-4): -0.3V to VLOGIC + 0.3V	SO Package (derate 6.7mW/°C above 70°C)696mW Plastic DIP (derate 10.53 mw/°C above 70°C)842mW Thin QFN (derate 21.3mW/°C above 70°C)1702mW
Operating Temperature Range: (Industrial)40°C to +85°C (Hi-Temp)55°C to +125°C	
Maximum Junction Temperature175°C	

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

V+ = 15V, V- = -15V, GND = 0V. Operating temperature range (unless otherwise noted).

	0/450	CONDITIONS		VLOGIC = 3.3V			VLOGIC = 5.0V			
PARAMETER	SYMBOL		FIGURE	MIN	ТҮР	MAX	MIN	TYP	MAX	UNIT
SWITCH PARAMETERS										
Switch Signal Range	VRANGE						-15		+15	V
Switch Resistance	Ron	25°C, 10mA -55°C to +125°C, 10mA	1 1	10 8		22 26	10 8		17 20	$\Omega \Omega$
Leakage	ISWLEAK	Switch voltage ± 15V, 25°C	2			5			5	nA
	ISWLEAK	Switch voltage ± 15V, 125°	2			20			20	nA
	ISWLEAK	Switch voltage ± 15V, -55°C	2			150			150	nA
LOGIC INPUTS	•			•	•	•				
Input High Voltage	VIH			70			70			%VLOGIC
Input Low Voltage	VIL					30			30	%VLOGIC
Input Current	lin	VIN = 0V or VIN=VLOGIC		-0.5		0.5	-0.5		0.5	μA
SUPPLY										
VLOGIC Current	IDD1	Any state				0.5			0.5	μA
V+ Current	DD2	Any state				0.5			0.5	μA
V- Current	IEE	Any state		-0.5			-0.5			μA
DYNAMIC PARAMETERS										
Turn On Time	Ton	V+/V- = ±10V, 25°C Vs = ±10V, -55°C to +125°C	3 3		55	75		35	55	ns ns
Turn Off time	Toff	V+/V- = ±10V, 25°C Vs = ±10V, -55°C to +125°C	3 3		35	40		20	25	ns ns
Break-Before-Make Time	TD	10V signal, 25°C 10V signal, -55°C to +125°C	4 4	4	8		4	8		ns ns
Charge Injection	Q	Vs=0V, Rs=0Ω, 25°C	5		4			4		рС
Off Isolation	RR	f = 1 MHz, 25°C	6		65			65		dB
Crosstalk	CR	f = 1 MHz, 25°C	7		90			90		dB
Capacitance	COFF CON	Switch Off, 25°C Switch On, 25°C	8 9		5 20			5 20		pF pF

TEST CIRCUITS

-15V

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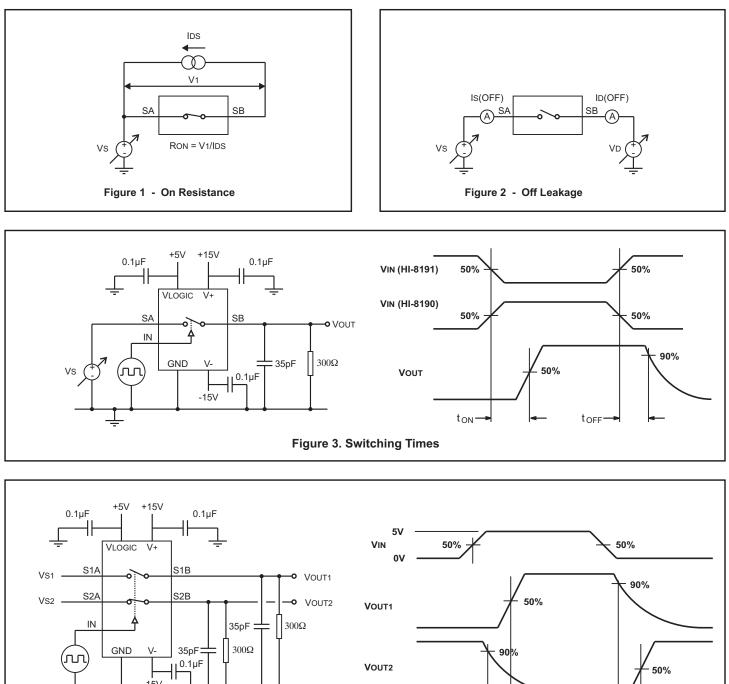
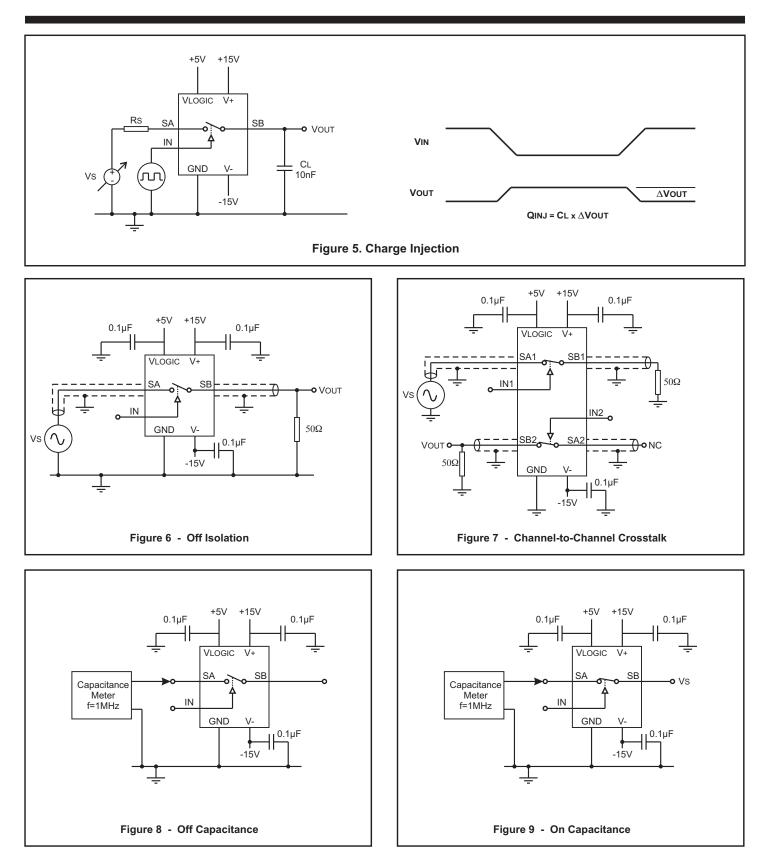


Figure 4. Break-Before-Make Time Delay (HI-8192)

t_D -

t_D

HI-8190, HI-8191, HI-8192



HOLT INTEGRATED CIRCUITS 6

FREQUENCY RESPONSE

Figure 10 shows a typical frequency response.

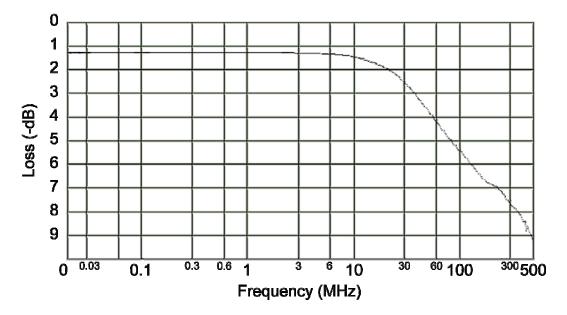


Figure 10. Frequency Response.

ORDERING INFORMATION

HI - <u>819x xx x x</u>

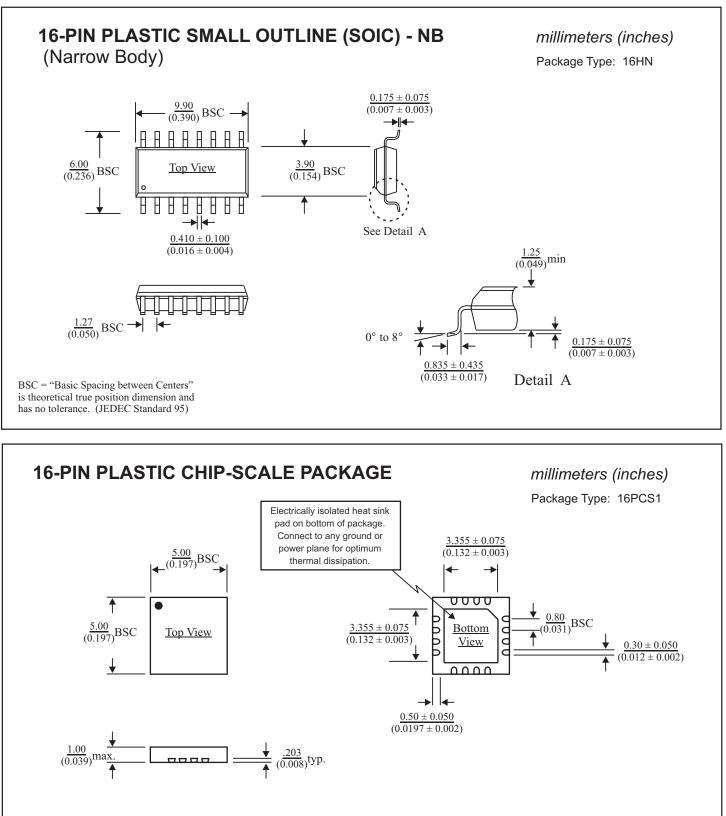
PART NUMBER	LEAD FINISH						
Blank	Tin / Lead (Sn / Pb) Solder						
F	100% Matte Tin (Pb-	free, Ro⊢)				
PART NUMBER	TEMPERATURE RANGE	FLOW	BURN IN				
1	-40°C TO +85°C	1	NO				
Т	-55°C TO +125°C	Т	NO				
М	-55°C TO +125°C	М	YES				
	PACKAGE DESCRIPTION						
PART NUMBER							
	DESCRIPTION	mm CHI	P SCALE (1	6PCS1) (No M-flow, Pb-free only)			
NUMBER	DESCRIPTION		`	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			
NUMBER PC	DESCRIPTION 16 PIN PLASTIC 5x5	ROW BC	`	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			
NUMBER PC PS	DESCRIPTION 16 PIN PLASTIC 5x5 16 PIN PLASTIC NAF	ROW BC	`	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			
NUMBER PC PS PD	DESCRIPTION 16 PIN PLASTIC 5x5 16 PIN PLASTIC NAF 16 PIN PLASTIC DIP	ROW BC	DDY SOIC (1	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			
NUMBER PC PS PD	DESCRIPTION 16 PIN PLASTIC 5x5 16 PIN PLASTIC NAF 16 PIN PLASTIC DIP FUNCTION	ROW BC (16P) RMALLY C	DDY SOIC (1	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			

REVISION HISTORY

P/N	Rev	Date	Description of Change
DS8190	New	10/26/11	Initial release
	А	12/12/11	Update DC and Peak switch current values in maximum ratings. Clarify QFN available only in Pb-free.
	В	09/26/12	Add frequency response curve.
	С	12/05/13	Add leakage vs switch voltage as a function of temperature curves. Update package drawings.
	D	10/26/17	Update frequency response curve.



HI-8190 PACKAGE DIMENSIONS



BSC = "Basic Spacing between Centers" is theoretical true position dimension and has no tolerance. (JEDEC Standard 95)



